

Matthew Hamer

List of Publications by Year in descending order

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Version: 2024-02-01

19
papers

1,382
citations

567247

15
h-index

752679

20
g-index

20
all docs

20
docs citations

20
times ranked

2651
citing authors

#	ARTICLE	IF	CITATIONS
1	Resonantly hybridized excitons in moiré superlattices in van der Waals heterostructures. <i>Nature</i> , 2019, 567, 81-86.	27.8	621
2	Interfacial ferroelectricity in marginally twisted 2D semiconductors. <i>Nature Nanotechnology</i> , 2022, 17, 390-395.	31.5	115
3	Nanometer Resolution Elemental Mapping in Graphene-Based TEM Liquid Cells. <i>Nano Letters</i> , 2018, 18, 1168-1174.	9.1	99
4	High Quality Factor Graphene-Based Two-Dimensional Heterostructure Mechanical Resonator. <i>Nano Letters</i> , 2017, 17, 5950-5955.	9.1	75
5	Indirect to Direct Gap Crossover in Two-Dimensional InSe Revealed by Angle-Resolved Photoemission Spectroscopy. <i>ACS Nano</i> , 2019, 13, 2136-2142.	14.6	63
6	Observing Imperfection in Atomic Interfaces for van der Waals Heterostructures. <i>Nano Letters</i> , 2017, 17, 5222-5228.	9.1	53
7	Infrared-to-violet tunable optical activity in atomic films of GaSe, InSe, and their heterostructures. <i>2D Materials</i> , 2018, 5, 041009.	4.4	52
8	Scalable Patterning of Encapsulated Black Phosphorus. <i>Nano Letters</i> , 2018, 18, 5373-5381.	9.1	43
9	Raman spectroscopy of GaSe and InSe post-transition metal chalcogenides layers. <i>Faraday Discussions</i> , 2021, 227, 163-170.	3.2	43
10	Gate-Defined Quantum Confinement in InSe-Based van der Waals Heterostructures. <i>Nano Letters</i> , 2018, 18, 3950-3955.	9.1	40
11	Formation and Healing of Defects in Atomically Thin GaSe and InSe. <i>ACS Nano</i> , 2019, 13, 5112-5123.	14.6	35
12	Ultra-thin van der Waals crystals as semiconductor quantum wells. <i>Nature Communications</i> , 2020, 11, 125.	12.8	33
13	Niobium diselenide superconducting photodetectors. <i>Applied Physics Letters</i> , 2019, 114, .	3.3	28
14	Optical second harmonic generation in encapsulated single-layer InSe. <i>AIP Advances</i> , 2018, 8, .	1.3	24
15	Enhanced Superconductivity in Few-Layer TaS ₂ due to Healing by Oxygenation. <i>Nano Letters</i> , 2020, 20, 3808-3818.	9.1	23
16	Atomic Resolution Imaging of CrBr ₃ Using Adhesion-Enhanced Grids. <i>Nano Letters</i> , 2020, 20, 6582-6589.	9.1	13
17	Ghost anti-crossings caused by interlayer umklapp hybridization of bands in 2D heterostructures. <i>2D Materials</i> , 2021, 8, 015016.	4.4	8
18	Strongly Absorbing Nanoscale Infrared Domains within Strained Bubbles at hBN/Graphene Interfaces. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 57638-57648.	8.0	7

#	ARTICLE	IF	CITATIONS
19	Moir $\sqrt{3}$ Superlattice Effects and Band Structure Evolution in Near-30-Degree Twisted Bilayer Graphene. ACS Nano, 2022, 16, 1954-1962.	14.6	6